

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

## PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	I⊵ Max Tc = +25°C (Note 7)
60)/	3.1mΩ @ V <sub>GS</sub> = 10V	100A
60V	4.5mΩ @ V <sub>GS</sub> = 4.5V	100A

## **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Primary switches in isolated DC-DC
- Synchronous rectifiers
- Load switches

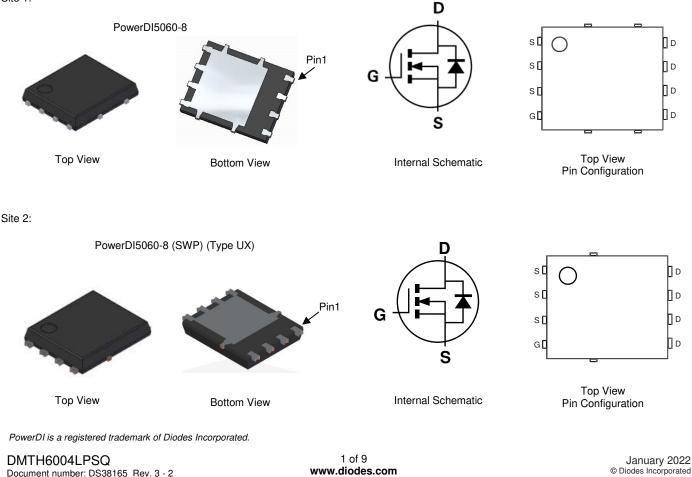
### **Features**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -• Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub> Minimizes Power Losses •
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6004LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

## **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)





Site 1:



## Ordering Information (Note 4)

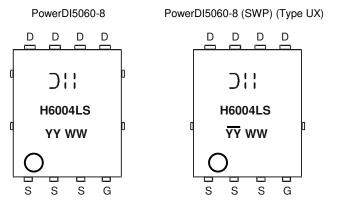
Part Number	Daakaga	Pa	Packing		
Part Number	Package	Qty.	Carrier		
DMTH6004LPSQ-13 PowerDI5060-8		2,500	Tape & Reel		
DMTH6004LPSQ-13         PowerDI5060-8 (SWP) (Type UX)         2,500         Tape & Reel					
tes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.					

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



### **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	22 16	А
Continuous Drain Current (Notes 6 & 7)	Tc = +25°C Tc = +100°C	ID	100 100	А
Maximum Continuous Body Diode Forward Current (Note 5)		ls	100	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	400	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	400	A
Avalanche Current, L = 0.2mH		las	40	A
Avalanche Energy, L = 0.2mH		Eas	160	mJ

## **Thermal Characteristic**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	47	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	138	W
Thermal Resistance, Junction to Case (Note 6)	·	Rejc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Limited by package.



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

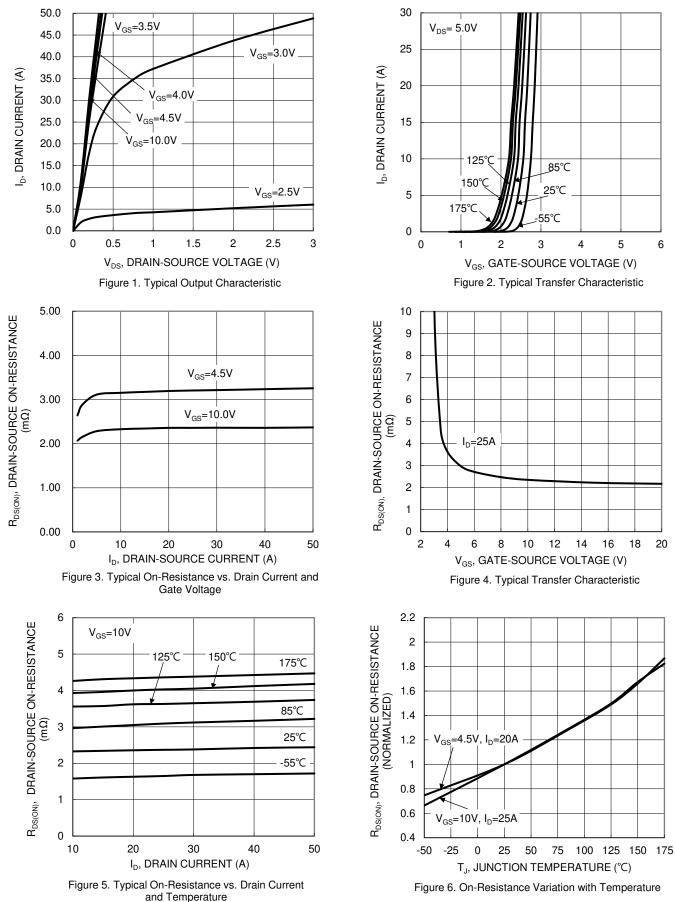
						-
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	60		—	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	—	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	VGS(TH)	1	—	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Decision	—	2.5	3.1	mΩ	$V_{GS} = 10V, I_D = 25A$
Static Drain-Source On-Resistance	RDS(ON)	—	3.3	4.5	mΩ	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 20A
Diode Forward Voltage	V <sub>SD</sub>	_	_	1.3	V	$V_{GS} = 0V, I_{S} = 25A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	5399	—		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f = 1MHz
Output Capacitance	Coss	_	1306	_	pF	
Reverse Transfer Capacitance	Crss	—	92	—		
Gate Resistance	Rg	_	0.64	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	78.3	—		
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	38.5	—	nC	V <sub>DD</sub> = 30V, I <sub>D</sub> = 25A
Gate-Source Charge	Q <sub>gs</sub>		10.2	—	no	
Gate-Drain Charge	Q <sub>gd</sub>	_	20.4	—		
Turn-On Delay Time	t <sub>D(ON)</sub>	—	9.9	_		$\label{eq:VDD} \begin{split} V_{DD} &= 30V, \ V_{GS} = 10V\\ I_D &= 25A, \ R_g = 3.5\Omega \end{split}$
Turn-On Rise Time	tR	—	17.7	—	ns	
Turn-Off Delay Time	tD(OFF)	—	53.5	_		
Turn-Off Fall Time	tF	—	32.9	—	1	
Body Diode Reverse Recovery Time	trr	_	49.7	_	ns	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	—	78.9	—	nC	IF = 25A, di/dt = 100A/µs

 Notes:
 8. Short duration pulse test used to minimize self-heating effect.

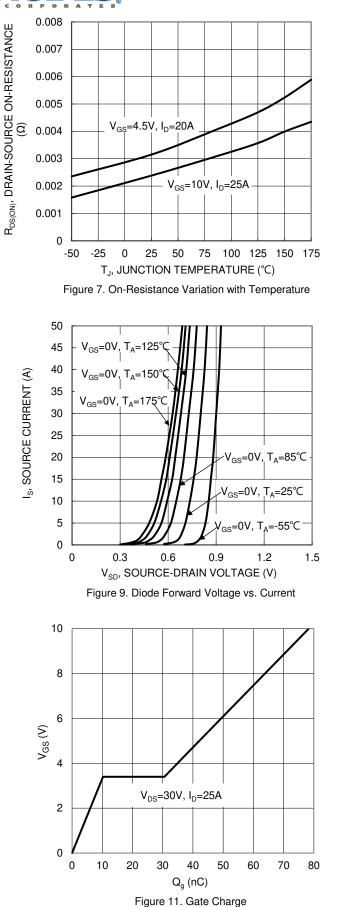
 9. Guaranteed by design. Not subject to production testing.

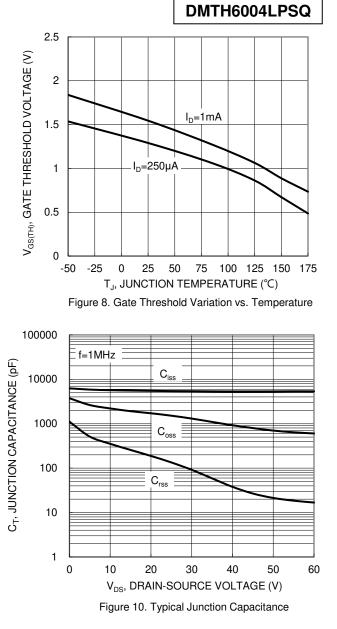


# DMTH6004LPSQ









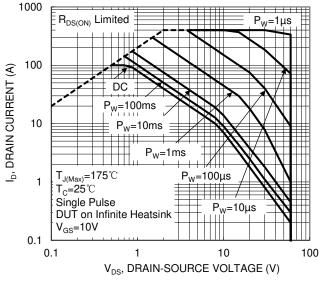
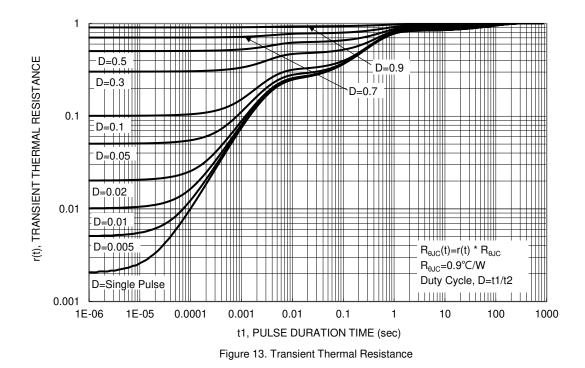


Figure 12. SOA, Safe Operation Area





DMTH6004LPSQ Document number: DS38165 Rev. 3 - 2

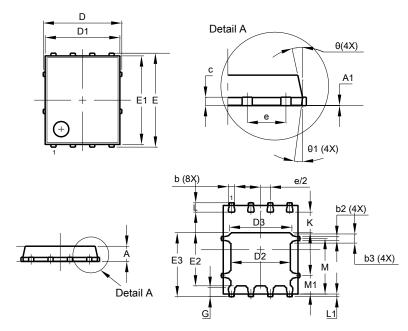


# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

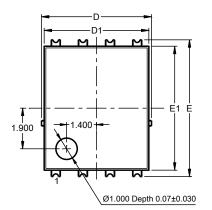
### Site 1:

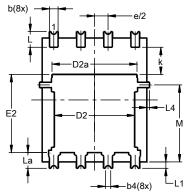




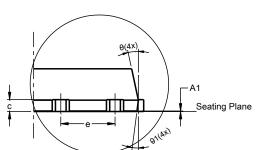
	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
C D	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC			
G	0.51	0.71	0.61		
К	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
Al	All Dimensions in mm				

Site 2:

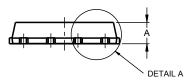




PowerDI5060-8 (SWP) (Type UX)



DETAIL A



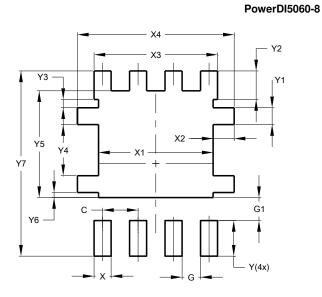
PowerDI5060-8 (SWP)				
(Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	(	).25REF		
С	0.230	0.330	0.277	
D	-	.15 BS(		
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
Е	6	.40 BS0	2	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е		.27BSC	)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0	.050RE	F	
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				



## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

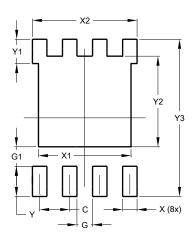
### Site 1:



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

### PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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